

Application Note

Evaluation Board : P/N VM209FE

Device : VM209F

[2-18] GHz 10W GaN power amplifier Evaluation board

	Written	Controlled by	Approved by
Name	DLA	GDE	
Date	01/07/25	01/07/25	
Signature	OK	OK	



I. HISTORIC

Edition	Date	Description of Evolutions
1.0	01/07/25	Creation

II. SUMMARY

I.	Historic.....	2
II.	Summary.....	2
III.	List of illustration.....	2
IV.	Introduction.....	3
	IV-1. Description.....	3
	IV-2. Evaluation Board photo.....	3
V.	Interface and components.....	4
	V-1. VM209FE interface.....	4
VI.	Biasing procedure and operating conditions.....	6
	VI-1. Electrical operating conditions.....	6
	VI-2. Biasing procedure.....	6
VII.	Absolute maximum rating.....	7
VIII.	Typical EVB Measurements results.....	7
	VIII-1. Measurements conditions.....	7
	VIII-2. S-Parameters.....	8
	VIII-3. Large Signal.....	10

III. LIST OF ILLUSTRATION

Figure 1.	VM209FE evaluation board with its dissipator.....	3
Figure 2.	Evaluation board VM209FE interface.....	4
Figure 3.	PCB cabling.....	5
Figure 4.	Losses estimation.....	7
Figure 5.	Gain (S ₂₁).....	8
Figure 6.	Input return loss (S ₁₁).....	8
Figure 7.	Output return loss (S ₂₂).....	9
Figure 8.	Output Power vs Input Power vs Frequency.....	10
Figure 9.	Gain vs Input Power vs Frequency.....	10
Figure 10.	Drain current vs Input Power vs Frequency.....	11
Figure 11.	Efficiency vs Input Power vs Frequency.....	11
Figure 12.	Saturated Output Power, Gain and Efficiency vs Frequency.....	12



IV. INTRODUCTION

IV-1. Description

The VM209FE is an evaluation board of the VM209F flange component. It is working in the [2-18] GHz frequency bandwidth.

The evaluation board is composed of 2 mains parts:

- VM209F [2-18] GHz 10W GaN power amplifier (1) in flange package
- Test structure support: PCB's with SMA/DC connectors and heatsink (2)

The test structure support uses a RF PCB with SMA connectors and second order decoupling components and connectors to bias the component, all this on an aluminum mechanical support screwed on a heat sink (with fan).

Supply cables are not provided.

This document describes the way to use the VM209FE Evaluation board

Typical RF results are included.

IV-2. Evaluation Board photo

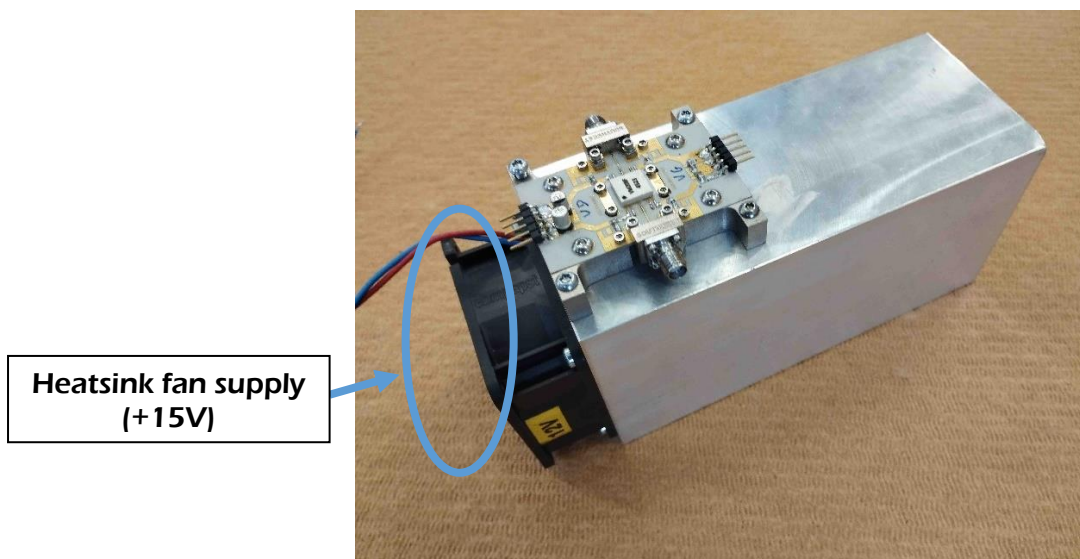


Figure 1. VM209FE evaluation board with its dissipator

V.INTERFACE AND COMPONENTS

V-1. VM209FE interface

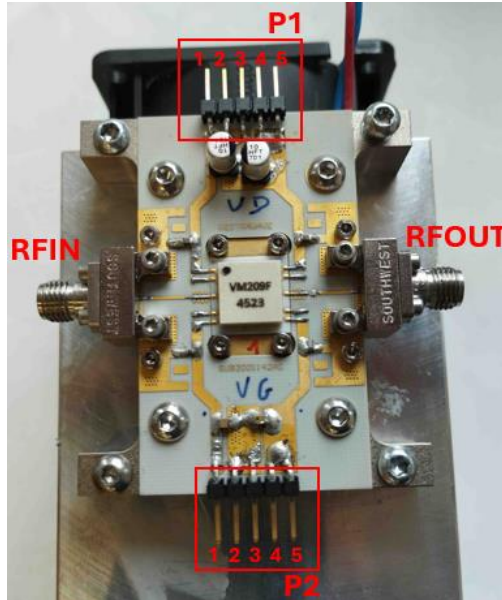


Figure 2. Evaluation board VM209FE interface

Connector	Type	Allocation
P1	DC connector	- V_D power supply - GND
P2	DC connector	- V_G power supply - GND
RF IN	SMA female	PA RF input
RF OUT	SMA female	PA RF output

P1	
PIN	P1 Identification
1	V_D
2	GND
3	GND
4	V_D
5	V_D

P2	
PIN	P2 Identification
1	V_G
2	GND
3	GND
4	V_G
5	V_G

Table 1. VM209FE PINOUT

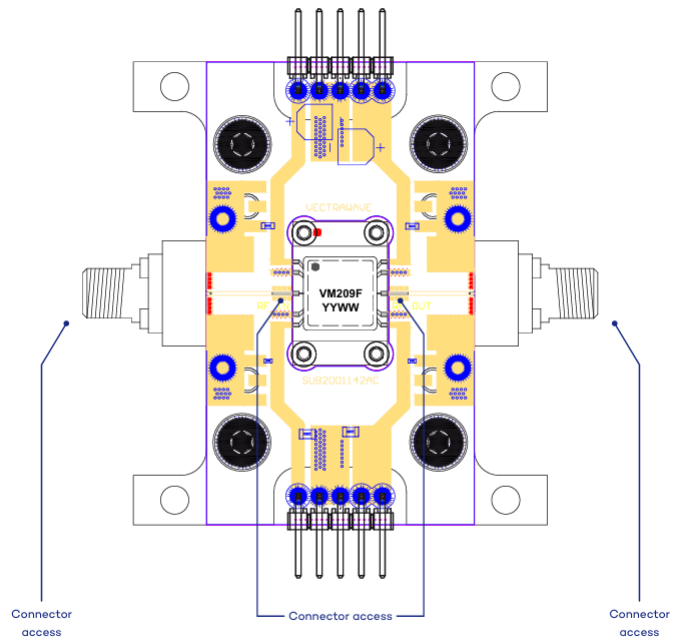
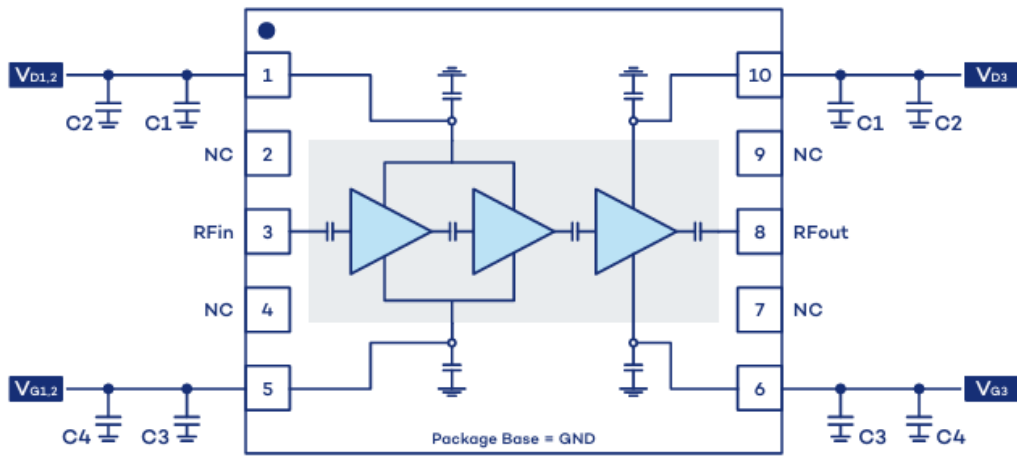


Figure 3. PCB cabling



Components	Value	Type
C4	100μF/6.3V	0805
C3	1μF/16V	0402
C2	1μF/50V	0603
C1	10μF / 50V	electrolytic

Table 2. External decoupling



VI. BIASING PROCEDURE AND OPERATING CONDITIONS

VI-1. Electrical operating conditions

- $V_D = +28V$
- $I_{DQ} = 1.12A$ (Typically $V_G = -1.7V$)
- RF CW
- Room temperature $25^\circ C$

VI-2. Biasing procedure

Switch on

1. Set V_G to 0V
2. Set V_D to 0V
3. Set +15V on dissipator fan
4. Set V_G to -3V
5. Set V_D to +28V
6. Increase V_G to obtain $I_{DQ} = 1.12A$ (Typically $V_G = -1.7V$)
7. Turn RF (CW) ON



- Always apply V_G before applying V_D
- Do not respect this may cause permanent damage on component.

Switch off

1. Turn RF OFF
2. Decrease V_G to -3V
3. Decrease V_D to 0V
4. Decrease V_G to 0V
5. Turn OFF dissipator fan



VII. ABSOLUTE MAXIMUM RATING

Symbols	Parameter	Max	Units
V_D	Drain voltage	35	V
I_D	Drain bias current	2.4	A
Pin	maximum input power overdrive	22	dBm

Table 5. Absolute Maximum Rating

Operation of this device above any of these parameters may cause permanent damages.

VIII. TYPICAL EVB MEASUREMENTS RESULTS

VIII-1. Measurements conditions

Reference plane measurements :

SMA connectors

Losses estimation :

For information, the losses of a 50Ohms line in the same structure and dimensions that the VM209FE Evaluation board RF PCB :

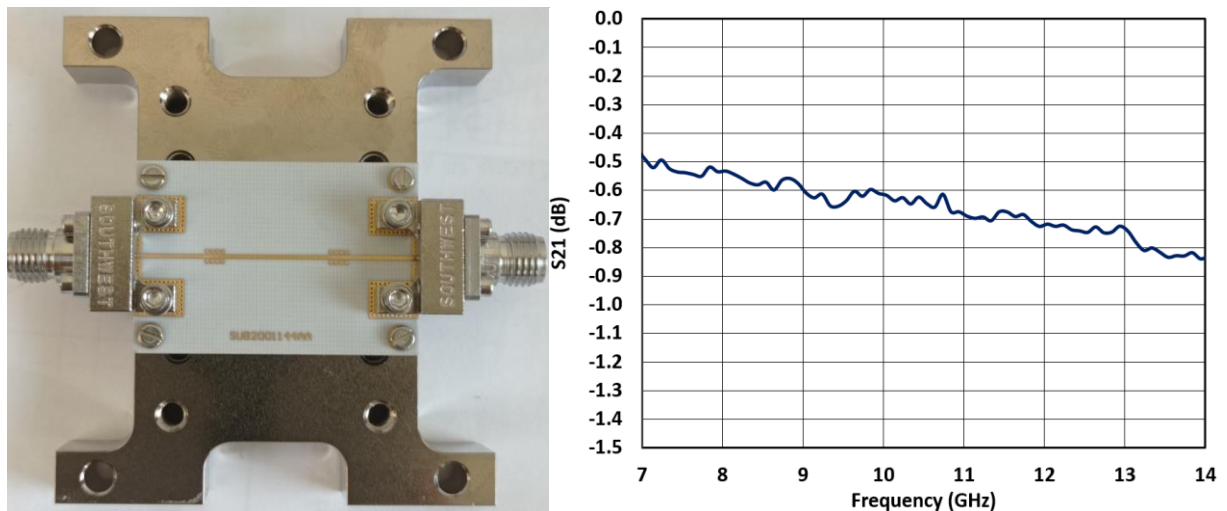


Figure 4. Losses estimation

50Ohms line S2P files can be provided on demand

VIII-2. S-Parameters

RF CW (Pin = -25 dBm).

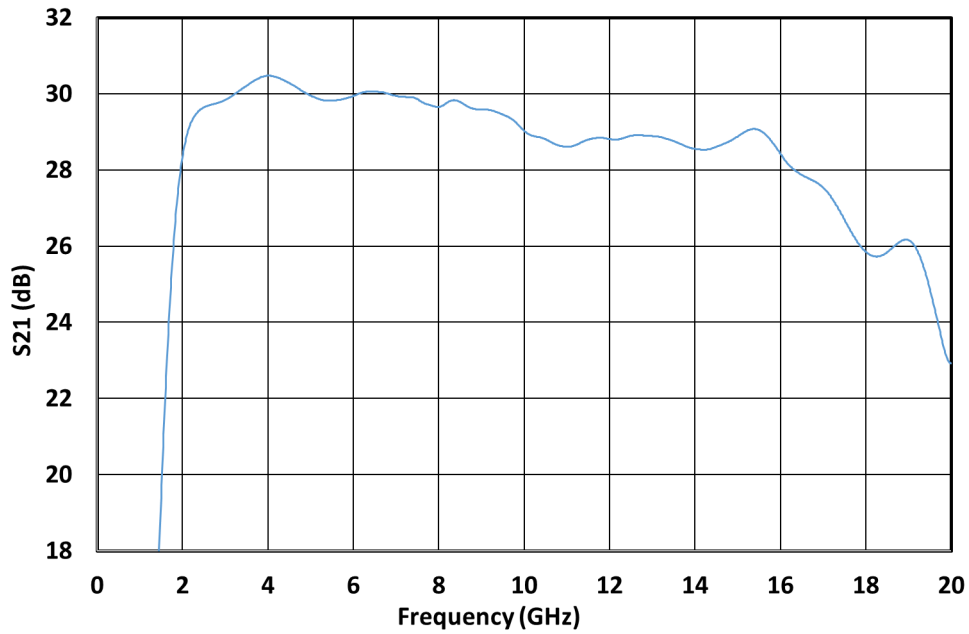


Figure 5. Gain (S21)

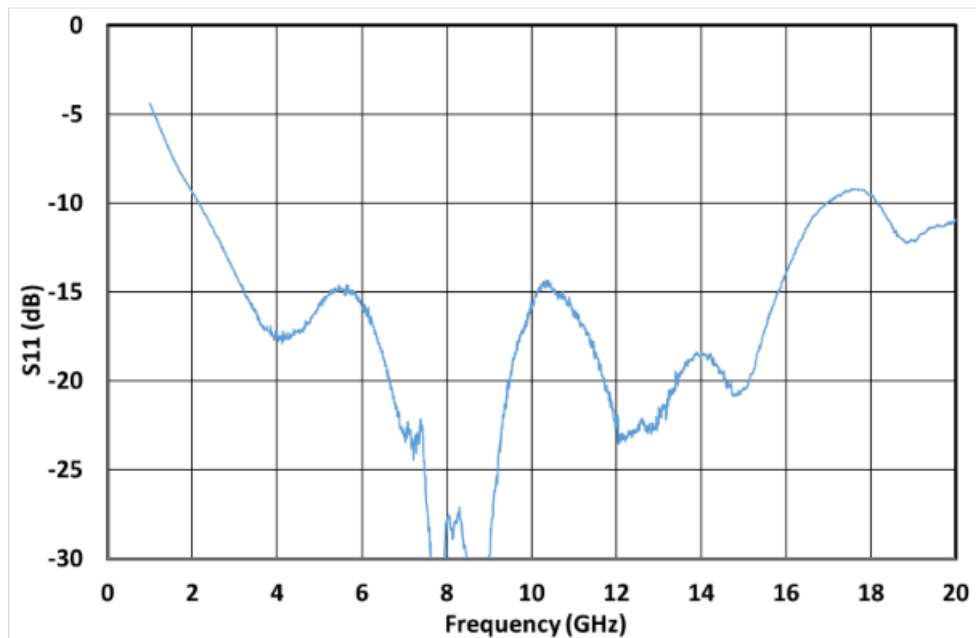


Figure 6. Input return loss (S11)



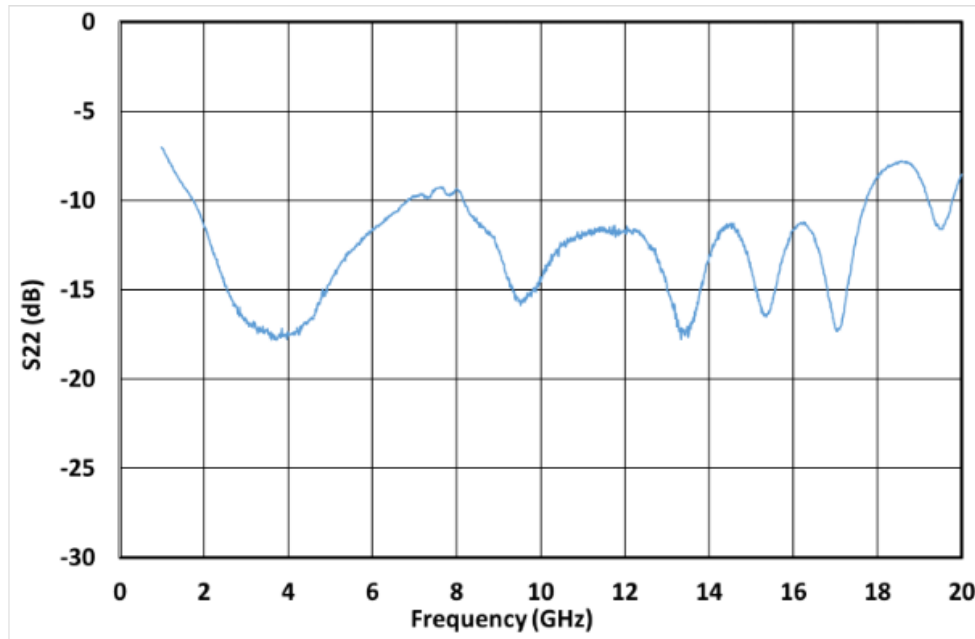


Figure 7. Output return loss (S22)



VIII-3. Large Signal

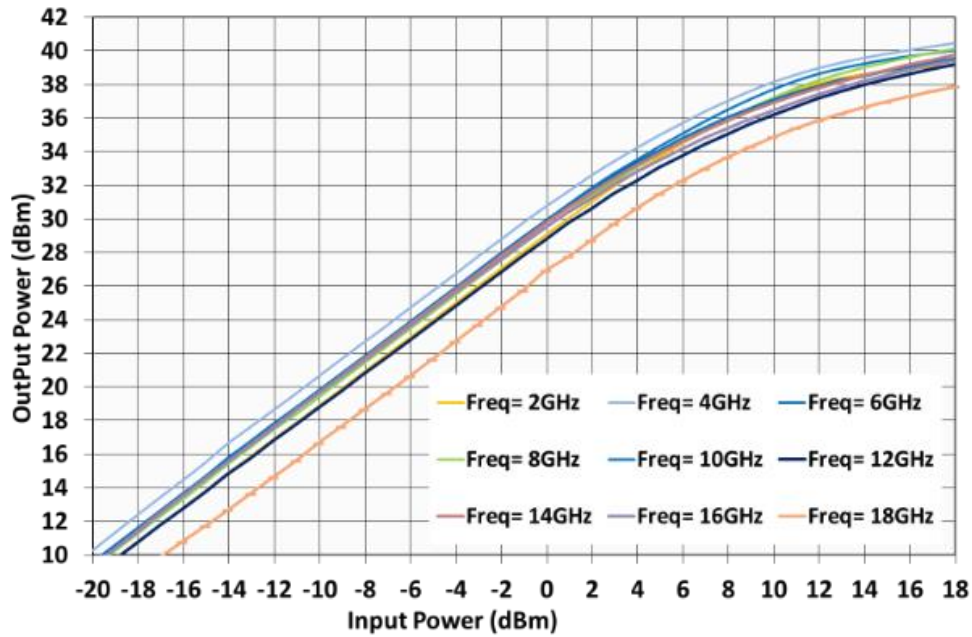


Figure 8. Output Power vs Input Power vs Frequency

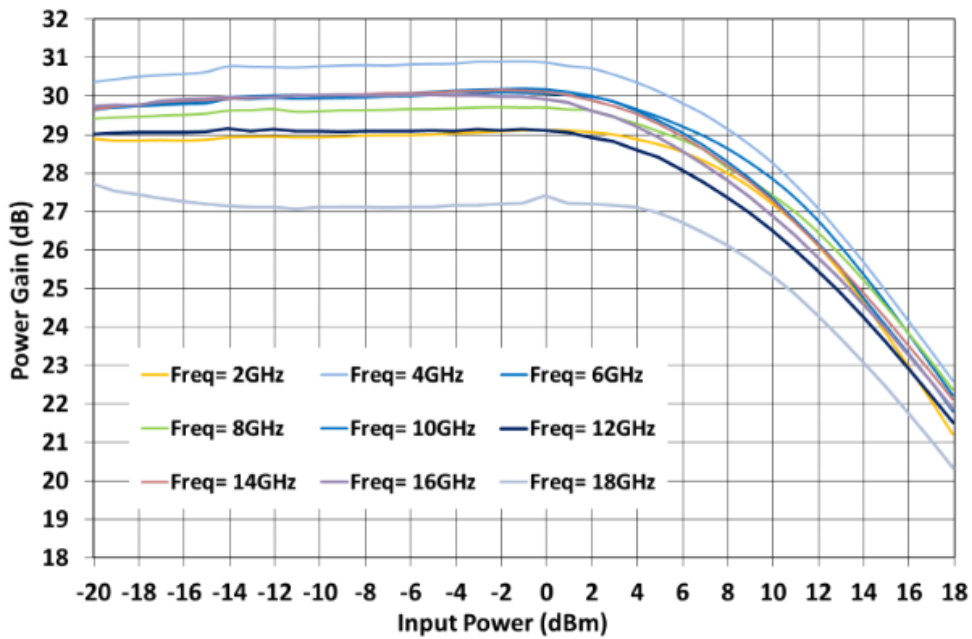


Figure 9. Gain vs Input Power vs Frequency



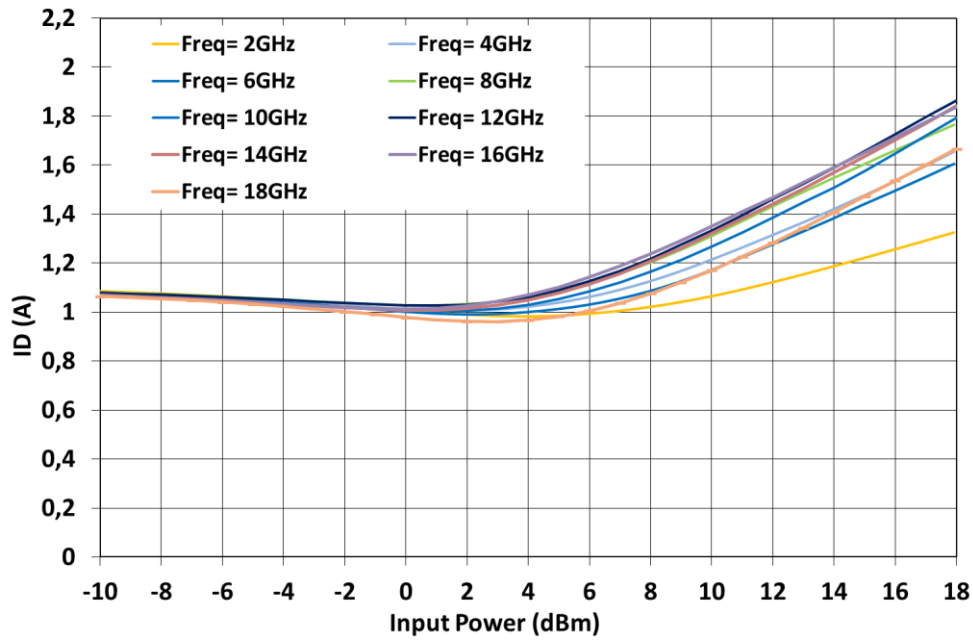


Figure 10. Drain current vs Input Power vs Frequency

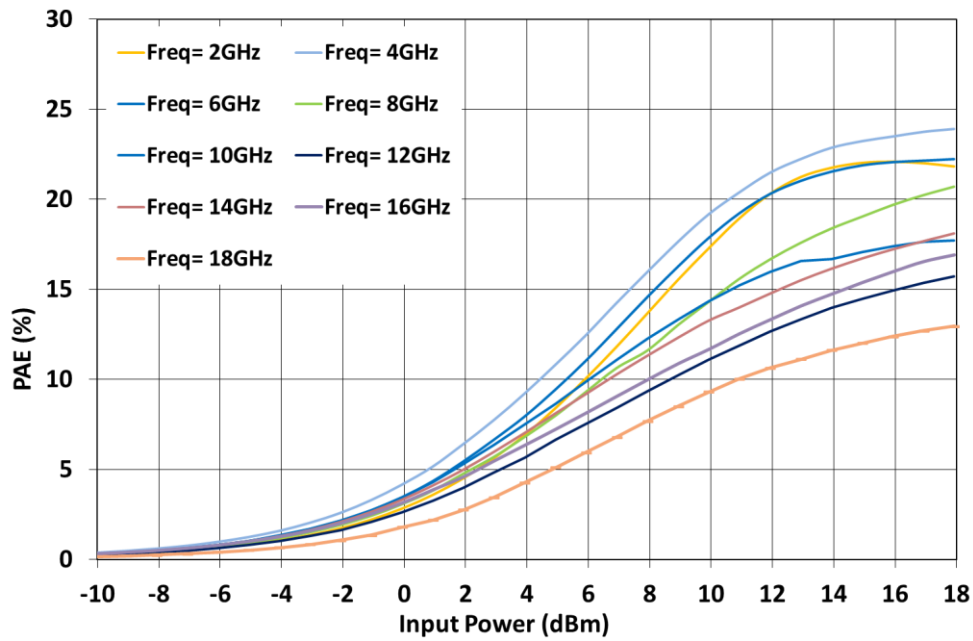


Figure 11. Efficiency vs Input Power vs Frequency



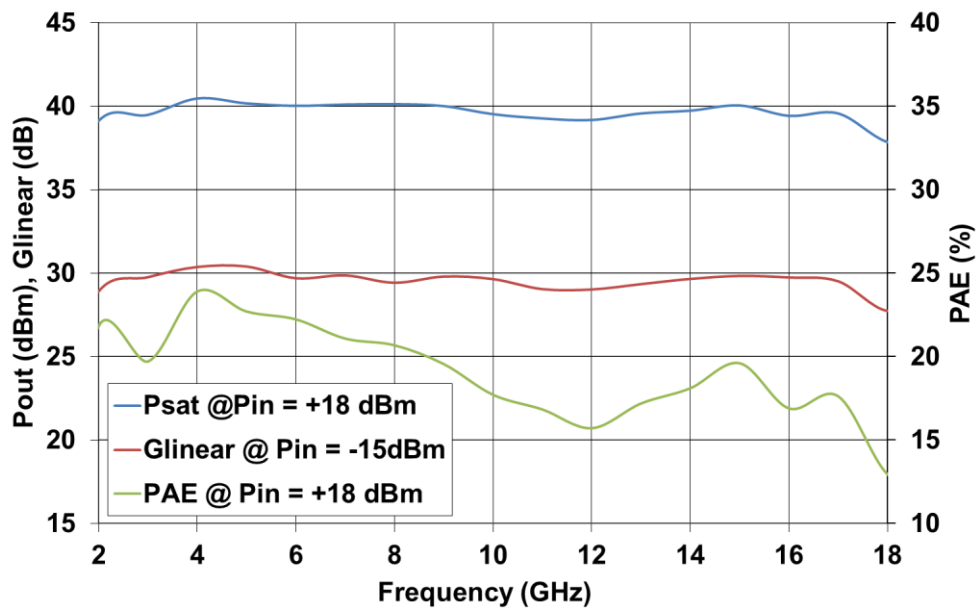


Figure 12. Saturated Output Power, Gain and Efficiency vs Frequency

End of document

